

No. 5701

LA4582CM**SANYO**

**Pre + Power Amplifier for
3-V Headphone Stereo Systems**

Overview

The LA4582CM is a preamplifier plus power amplifier IC that support auto-reverse, and was developed for 3-V headphone stereo systems.

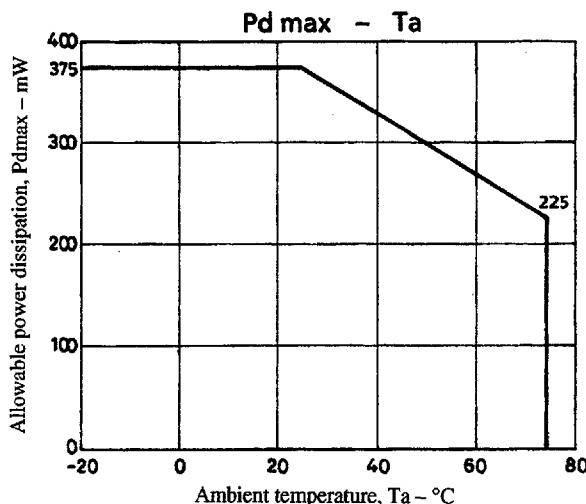
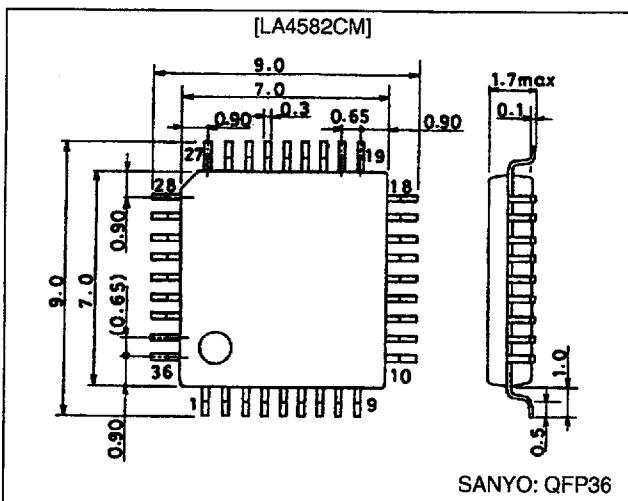
Features

- The LA4582CM was developed for cassette playback systems, and in addition to preamplifier and power amplifier functions, it also provides low boost and automatic power limitation (PVSS: Peak Volume Select System) functions.

- Provided in a 36-pin miniature flat package (0.65 mm lead pitch) that is optimal for set miniaturization.
- Capable of driving 8- Ω speakers
- Two-channel playback auto-reverse preamplifier
- Two-channel headphone power amplifier
- Low-frequency boost function (auto-loudness effect)
- Output suppression function (PVSS)
- Two-channel radio input switch (pre-mute switch)
- Power mute switch

Package Dimension

unit: mm



Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		4.5	V
Allowable power dissipation	P _d max		375	mW
Operating temperature	T _{opr}		-20 to +75	°C
Storage temperature	T _{stg}		-40 to +150	°C

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		3.0	V
Operating voltage range	V _{CC} op		1.8 to 3.6	V

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LA4582CM

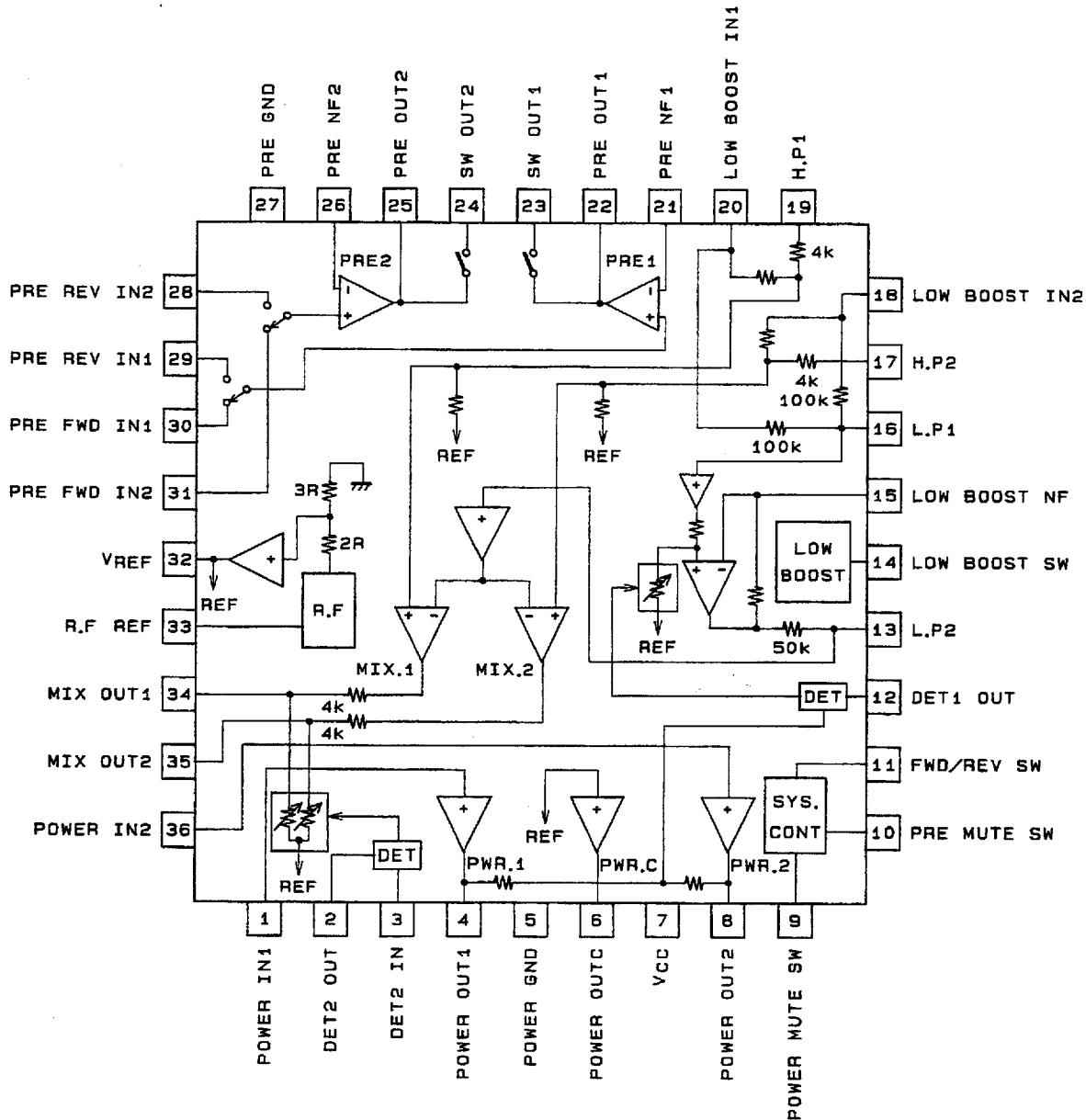
Operating Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 3.0 \text{ V}$, $f_i = 1 \text{ kHz}$, $0.775 \text{ V} = 0 \text{ dBm}$

$R_L = 10 \text{ k}\Omega$ (preamplifier), $R_L = 30 \text{ k}\Omega$ (low boost), $R_L = 16 \Omega$ (power amplifier)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[PRE + L BOOST + PVSS + POWER]						
Quiescent current	I_{CC01}	$R_g = 2.2 \text{ k}\Omega$, low boost off, PVSS off	13	19	29	mA
	I_{CC02}	$R_g = 2.2 \text{ k}\Omega$, low boost on, PVSS on	14	20	30	mA
Voltage gain (closed loop)	V_{G_T}	$V_O = -5 \text{ dBm}$	62.5	64.5	67.5	dB
[Preamplifier]						
Voltage gain (open loop)	V_{G_0}	$V_O = -5 \text{ dBm}$	70	83		dB
Voltage gain (closed loop)	V_{G_1}	$V_O = -5 \text{ dBm}$		40		dB
Maximum output voltage	$V_O \text{ max1}$	$\text{THD} = 1\%$, $V_{CC} = 1.8 \text{ V}$	0.1	0.2		V
Total harmonic distortion	THD_1	$V_O = 0.2 \text{ V}$, $VG = 40 \text{ dB/NAB}$		0.05	0.5	%
Equivalent input noise voltage	V_{NI}	$R_g = 2.2 \text{ k}\Omega$, BPF = 20 Hz to 20 kHz		1.3	2.0	μV
Crosstalk	CT_1	$R_g = 2.2 \text{ k}\Omega$, TUNE 1 kHz	60	80		dB
Ripple rejection	Rr_1	$R_g = 2.2 \text{ k}\Omega$, $V_{CC} = 1.8 \text{ V}$, $V_r = -20 \text{ dBm}$, $f_r = 100 \text{ Hz}$	40	50		dB
[Power Amplifier]						
Output power	P_O	$\text{THD} = 10\%$	23	34		mW
Voltage gain (closed loop)	V_{G_2}	$V_O = -5 \text{ dBm}$	27	29	32	dB
Total harmonic distortion	THD_2	$P_O = 1 \text{ mW}$		0.4	1.0	%
Interchannel crosstalk	CT_2	$V_O = -5 \text{ dBm}$, $R_V = 0 \Omega$	30	40		dB
Output noise voltage	V_{NO1}	$R_V = 0 \Omega$, BPF = 20 Hz to 20 kHz		25	40	μV
Ripple rejection	Rr_2	$R_V = 0 \Omega$, $V_r = -20 \text{ dBm}$, $f_r = 100 \text{ Hz}$, $V_{CC} = 1.8 \text{ V}$	45	55		dB
Input resistance	R_i		22	30	38	$\text{k}\Omega$
DC offset voltage	$V_{ODC \text{ OFF}}$	Between pin 8 and pins 4 to 6	-90		+90	mV
[L BOOST]						
Voltage gain	V_{G_3}	$V_{IN} = -30 \text{ dBm}$, boost: on/off	-2.3	-3.8	-5.3	dB
Boost	BST_1	$V_{IN BST} = -30 \text{ dBm}$, $f = 100 \text{ Hz}$, boost: on	11.2	14.7	18.2	dB
	BST_2	$V_{IN BST} = -30 \text{ dBm}$, $f = 10 \text{ Hz}$, boost: on	7.0	8.5	10	dB
Maximum output voltage	$V_O \text{ max2}$	$\text{THD} = 1\%$, boost: on	0.3	0.5		V
Total harmonic distortion	THD_3	$V_O = 0.1 \text{ V}$, boost: on		0.04	0.5	%
Interchannel crosstalk	CT_3	$V_O = -20 \text{ dBm}$, $R_g = 0$, boost: on	25	32		dB
Output noise voltage	V_{NO2}	$R_g = 0$, BPF = 20 Hz to 20 kHz, boost: off		2.0	5.0	μV
Ripple rejection	Rr_3	$R_g = 0$, $f_R = 100 \text{ Hz}$, $V_R = -20 \text{ dBm}$, $V_{CC} = 1.8 \text{ V}$, boost: on	45	53		dB
[L BOOST + PVSS + POWER] $R_V = 30 \text{ k}\Omega \text{ max}$						
Voltage gain	V_{G_4}	$V_{IN} = -40 \text{ dBm}$, $f = 1 \text{ kHz}$, boost: on/off	22.0	24.5	28.0	dB
Low boost output voltage	V_O1	$V_{IN} = -43 \text{ dBm}$, $f = 100 \text{ Hz}$, boost: on	0.13	0.23	0.33	V
	V_O2	$V_{IN} = -28 \text{ dBm}$, $f = 100 \text{ Hz}$, boost: on	0.25	0.4	0.55	V
Low boost total harmonic distortion	THD_4	$V_{IN} = -40 \text{ dBm}$, $f = 100 \text{ Hz}$, boost: on		0.5	1.2	%
PVSS voltage	V_O3	$V_{IN} = -40 \text{ dBm}$, PVSS2	-40	-37	-34	dBm
PVSS width	W_{PVSS}	Input increment between the point where operation starts and the point where the output is +4 dB from there. PVSS: on	30	40		dB
PVSS total harmonic distortion	THD_5	$V_{IN} = -40 \text{ dBm}$, PVSS2		0.5	1.2	%
PVSS start input	V_{OPIN}	PVSS2	-67	-63	-59	dBm

Note: The amount of boost for a 1-kHz signal.

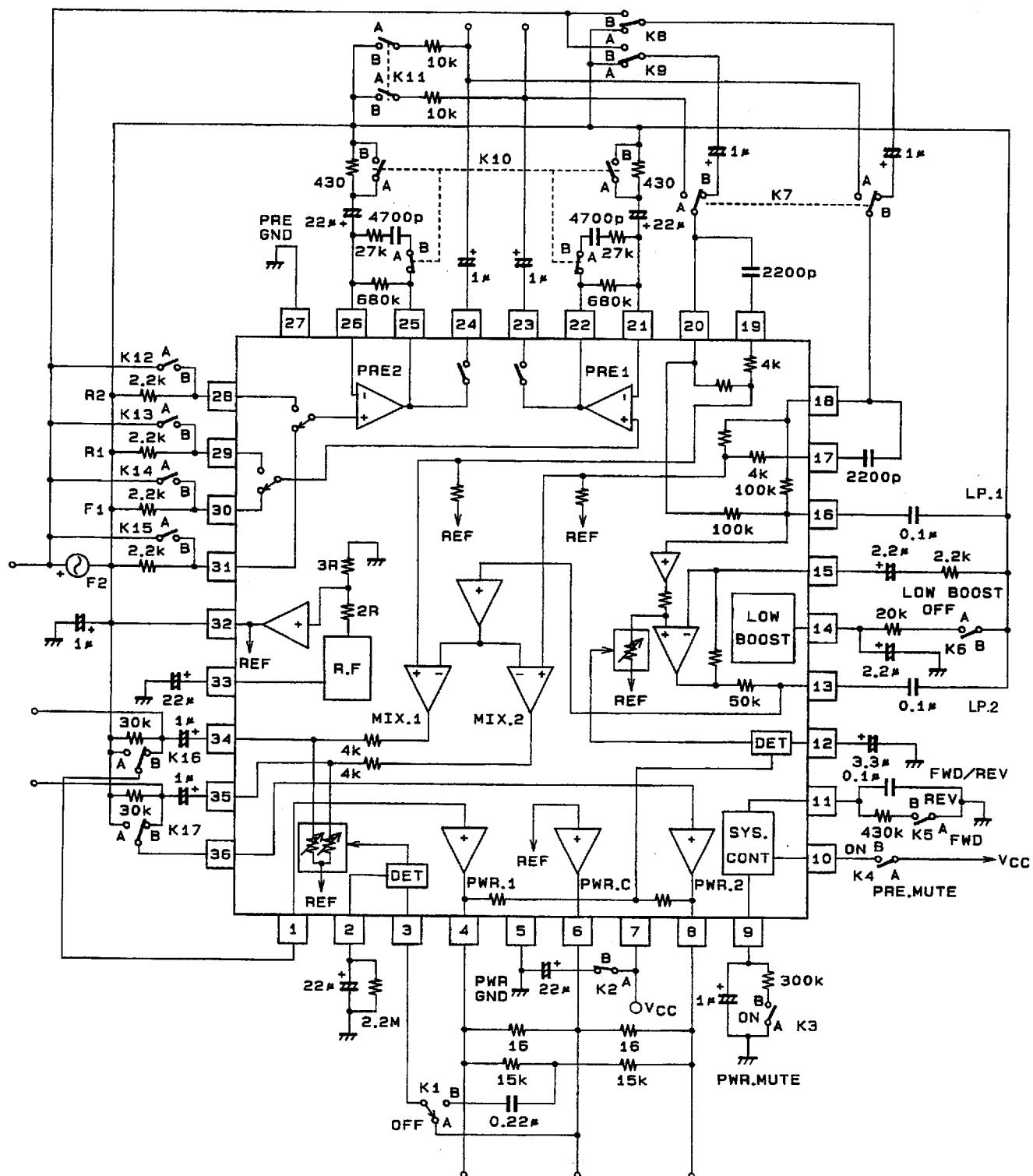
Block Diagram



A04517
Unit (Resistance: Ω)

LA4582CM

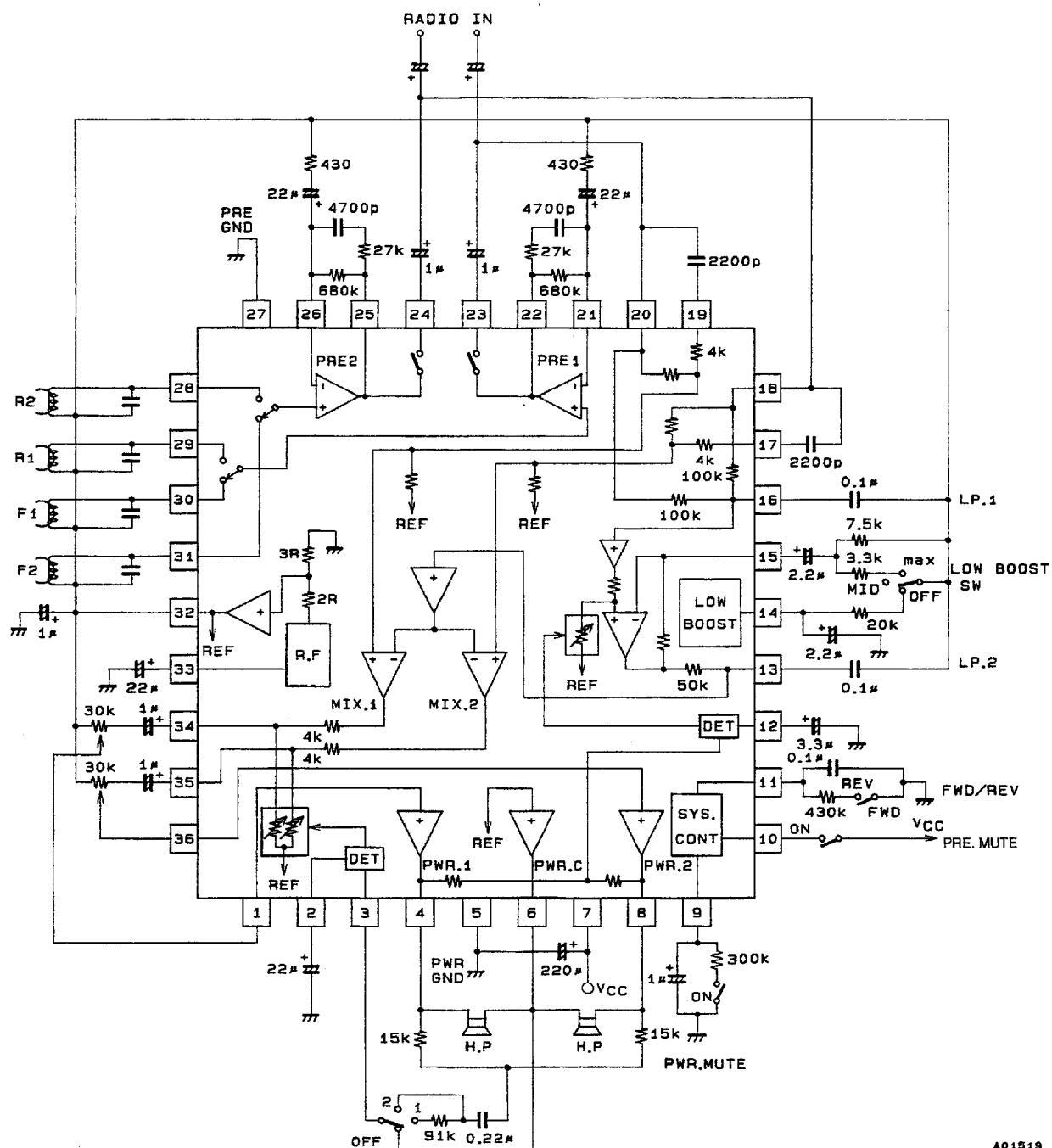
Test Circuit



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Unit (Resistance: Ω, Capacitance: F)

Sample Application Circuit



A01519

Unit (Resistance: Ω , Capacitance: F)